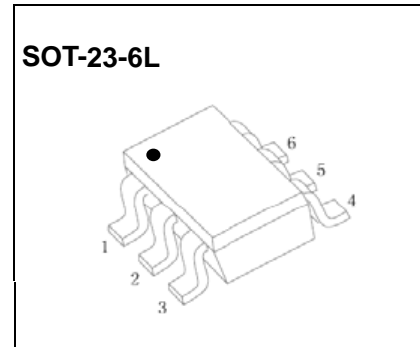




SOT-23-6L Plastic-Encapsulate MOSFETs

CJL2623 Dual P-Channel MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
-30V	130mΩ@-10V	-3A
	180mΩ@-4.5V	



FEATURE

- TrenchFET Power MOSFET
- Low Gate Charge
- Low On-resistance
- Surface Mount Package

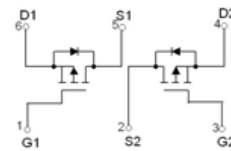
APPLICATION

- DC/DC converter
- Load switch for portable devices
- Commercial-industrial applications

MARKING:



Equivalent Circuit



ABSOLUTE MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-3	A
Pulsed Drain Current (note 1)	I_{DM}	-20	A
Power Dissipation (note 2)	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$
Junction Temperature	T_J	150	$^\circ\text{C}$
Storage Temperature	T_{STG}	-55~ 150	$^\circ\text{C}$

- Notes :**
1. Pulse width limited by Max.junction temperature.
 - 2.Per element must not be exceeded

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^\circ\text{C}$ unless otherwise specified

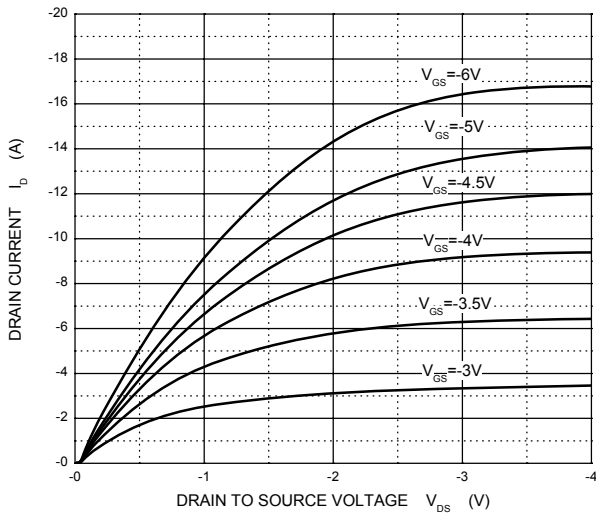
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC PARAMETERS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -30V, V_{GS} = 0V$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1		-3	V
Drain-source on-resistance (note 3)	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -3A$			130	$m\Omega$
		$V_{GS} = -4.5V, I_D = -2A$			180	$m\Omega$
Forward tranconductance	g_{FS}	$V_{DS} = -5V, I_D = -2A$		2		S
Diode forward voltage (note 3)	V_{SD}	$I_S = -1A, V_{GS} = 0V$			-1.2	V
DYNAMIC PARAMETERS (note 4)						
Input Capacitance	C_{iss}	$V_{DS} = -25V, V_{GS} = 0V, f = 1MHz$			240	pF
Output Capacitance	C_{oss}			42		pF
Reverse Transfer Capacitance	C_{rss}			32		pF
SWITCHING PARAMETERS (note 3,4)						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15V, V_{GS} = -10V, I_D = -1A$ $R_D = 15\Omega, R_G = 3.3\Omega$		5		ns
Turn-on rise time	t_r			6		ns
Turn-off delay time	$t_{d(off)}$			15		ns
Turn-off fall time	t_f			3		ns
Total Gate Charge	Q_g	$V_{DS} = -24V, V_{GS} = -4.5V, I_D = -2A$			4.5	nC
Gate-Source Charge	Q_{gs}			0.5		nC
Gate-Drain Charge	Q_{gd}			1.4		nC

Notes : 3. Pulse Test : Pulse width $\leq 300\mu s$, duty cycles $\leq 2\%$.

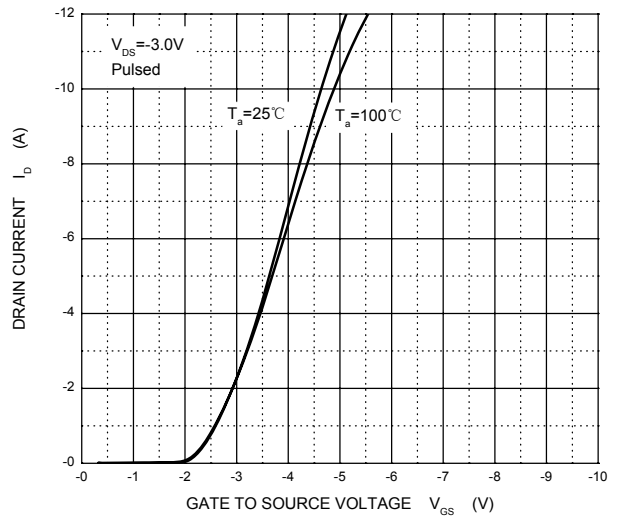
4. Granted by design, not subject to production testing.

Typical Characteristics

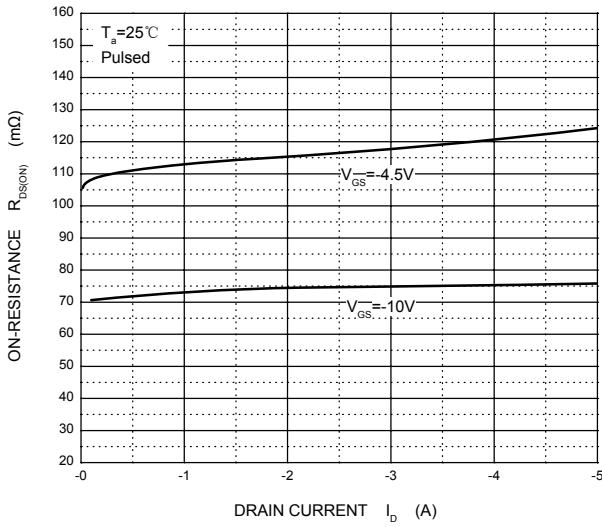
Output Characteristics



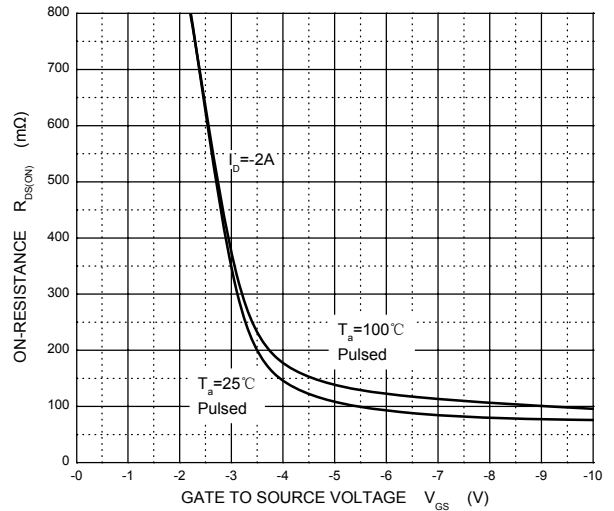
Transfer Characteristics



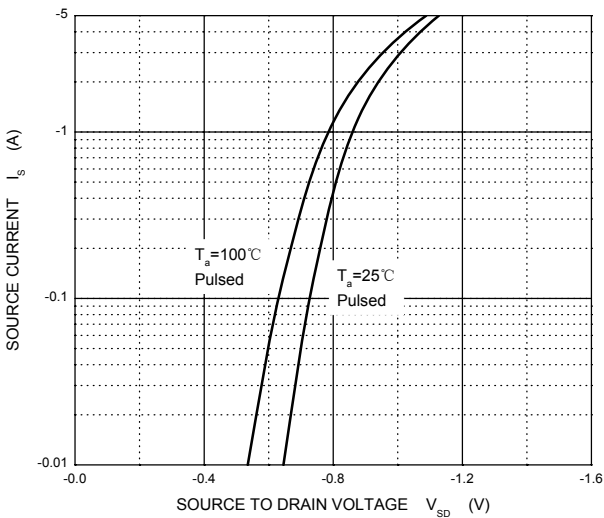
$R_{DS(ON)}$ — I_D



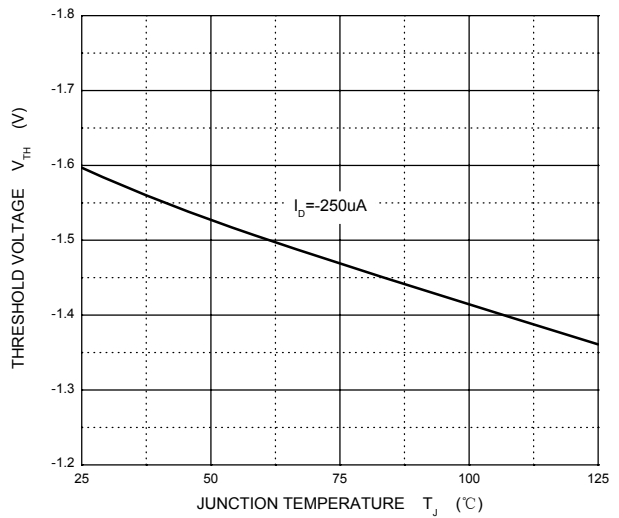
$R_{DS(ON)}$ — V_{GS}



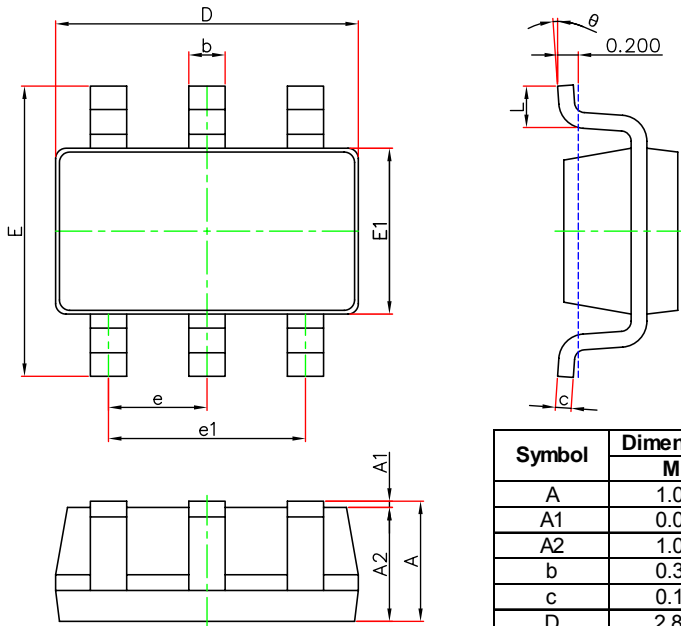
I_S — V_{SD}



Threshold Voltage

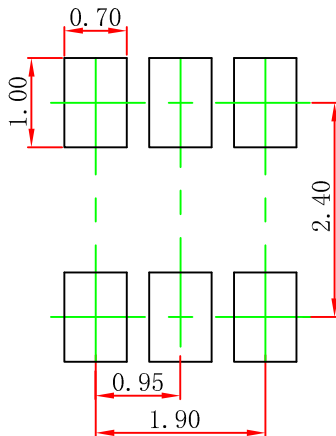


SOT-23-6L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SOT-23-6L Suggested Pad Layout



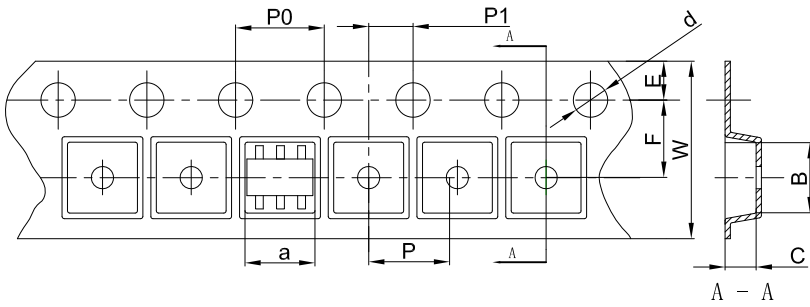
- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05 mm.
 3. The pad layout is for reference purposes only.

NOTICE

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SOT-23-6L Tape and Reel

SOT-23-6L Embossed Carrier Tape

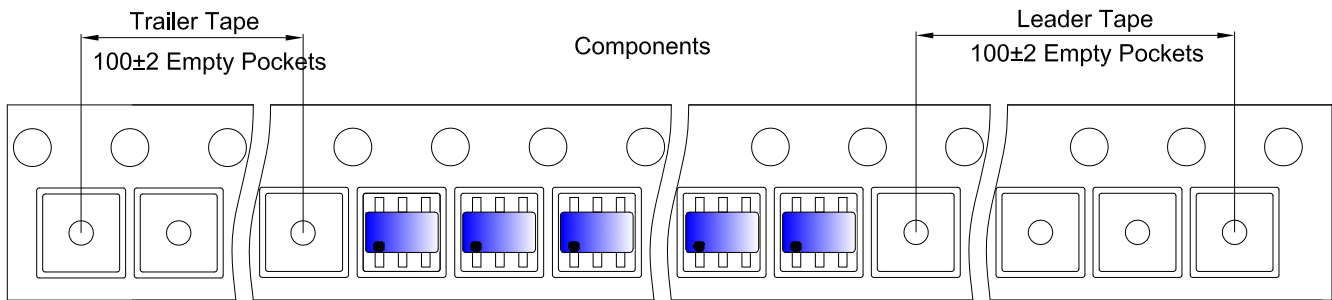


Packaging Description:

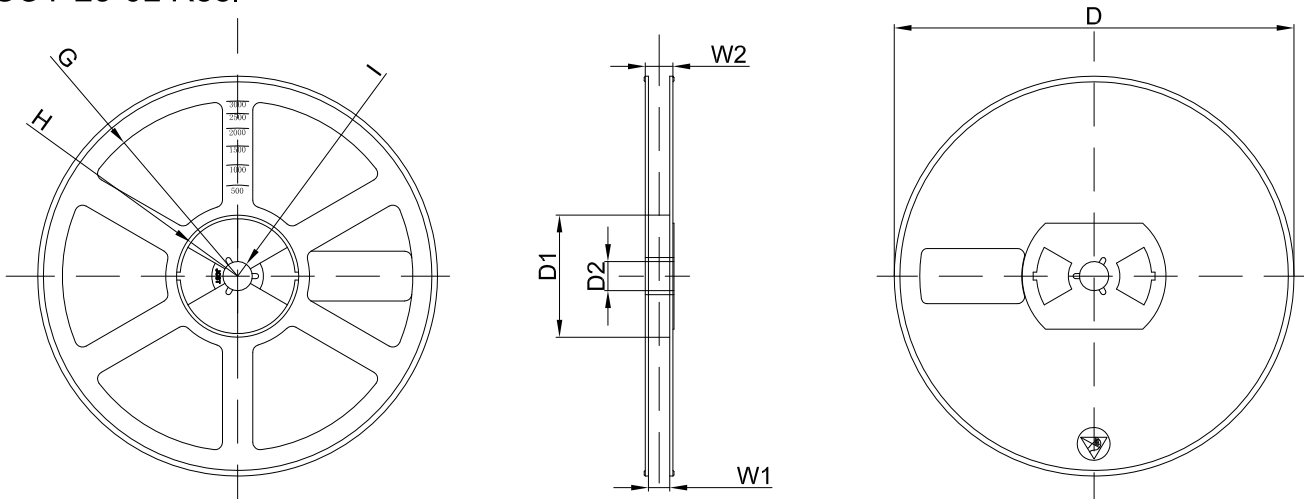
SOT-23-6L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 18.0cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOT-23-6L	3.17	3.23	1.37	Ø1.55	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23-6L Tape Leader and Trailer



SOT-23-6L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

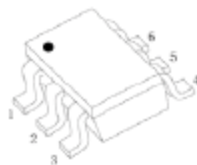
REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	

SOT-23-6L Plastic-Encapsulate MOSFETs

CJL2623 Dual P-Channel MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
-30V	130m Ω @-10V	-3A
	180m Ω @-4.5V	

SOT-23-6L



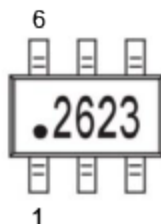
FEATURE

- TrenchFET Power MOSFET
- Low Gate Charge
- Low On-resistance
- Surface Mount Package

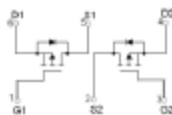
APPLICATION

- DC/DC converter
- Load switch for portable devices
- Commercial-industrial applications

MARKING:



Equivalent Circuit



ABSOLUTE MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	-30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	I_D	-3	A
Pulsed Drain Current (note 1)	I_{DM}	-20	A
Power Dissipation (note 2)	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^{\circ}\text{C}/\text{W}$
Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature	T_{STG}	-55~150	$^{\circ}\text{C}$

Notes : 1. Pulse width limited by Max.junction temperature.

2.Per element must not be exceeded

MOSFET ELECTRICAL CHARACTERISTICS

$T_a=25^\circ\text{C}$ unless otherwise specified

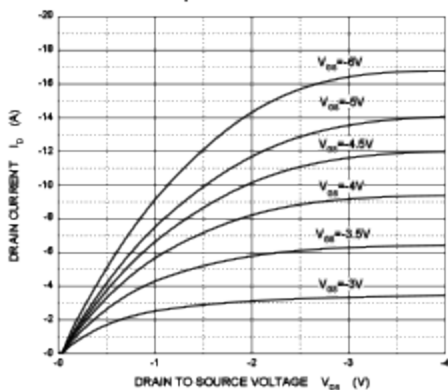
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
STATIC PARAMETERS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Zero gate voltage drain current	I_{DSS}	$V_{DS} = -30V, V_{GS} = 0V$			-1	μA
Gate-body leakage current	I_{GBS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1		-3	V
Drain-source on-resistance (note 3)	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -3A$			130	m Ω
		$V_{GS} = -4.5V, I_D = -2A$			180	m Ω
Forward transconductance	g_{FS}	$V_{DS} = -5V, I_D = -2A$		2		S
Diode forward voltage (note 3)	V_{SD}	$I_S = -1A, V_{GS} = 0V$			-1.2	V
DYNAMIC PARAMETERS (note 4)						
Input Capacitance	C_{iss}	$V_{DS} = -25V, V_{GS} = 0V, f = 1MHz$			240	pF
Output Capacitance	C_{oss}			42		pF
Reverse Transfer Capacitance	C_{rss}			32		pF
SWITCHING PARAMETERS (note 3,4)						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = -15V, V_{GS} = -10V, I_D = -1A$ $R_D = 15\Omega, R_G = 3.3\Omega$		5		ns
Turn-on rise time	t_r			8		ns
Turn-off delay time	$t_{d(off)}$			15		ns
Turn-off fall time	t_f			3		ns
Total Gate Charge	Q_g	$V_{DS} = -24V, V_{GS} = -4.5V, I_D = -2A$			4.5	nC
Gate-Source Charge	Q_{gs}			0.5		nC
Gate-Drain Charge	Q_{gd}			1.4		nC

Notes : 3. Pulse Test : Pulse widths $\leq 300\mu s$, duty cycles $\leq 2\%$.

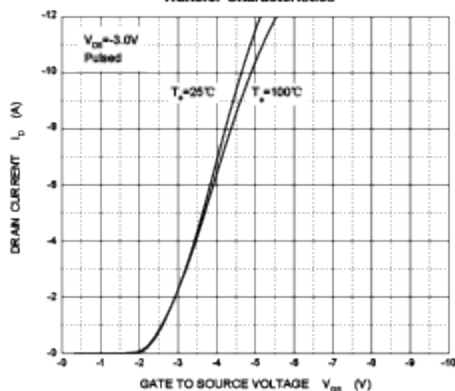
4. Guaranteed by design, not subject to production testing.

Typical Characteristics

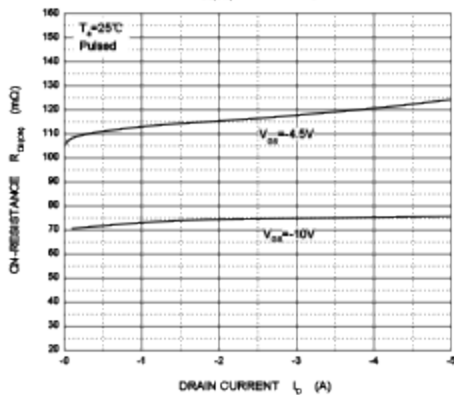
Output Characteristics



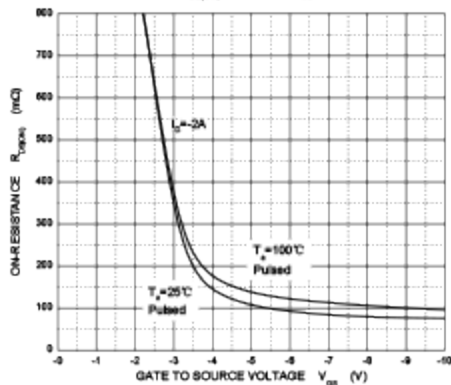
Transfer Characteristics



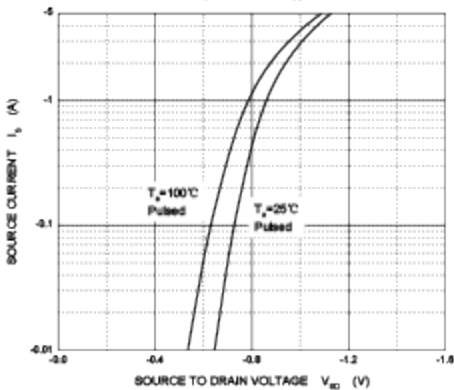
$R_{DS(on)}$ — I_D



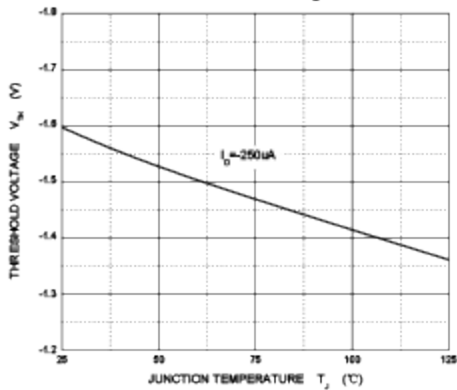
$R_{DS(on)}$ — V_{GS}



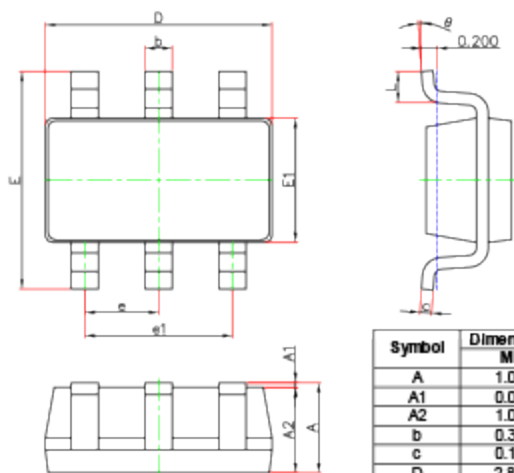
I_S — V_{SD}



Threshold Voltage

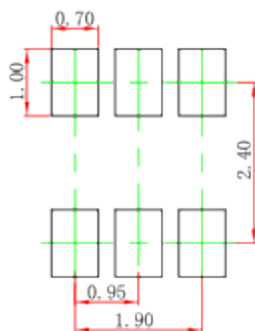


SOT-23-6L Package Outline Dimensions



Symbol	Dimensions in Millimeters		Dimensions in Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SOT-23-6L Suggested Pad Layout



Note:

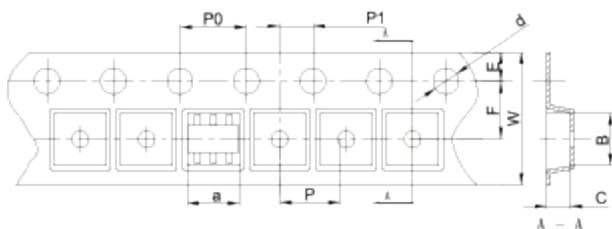
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

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SOT-23-6L Tape and Reel

SOT-23-6L Embossed Carrier Tape

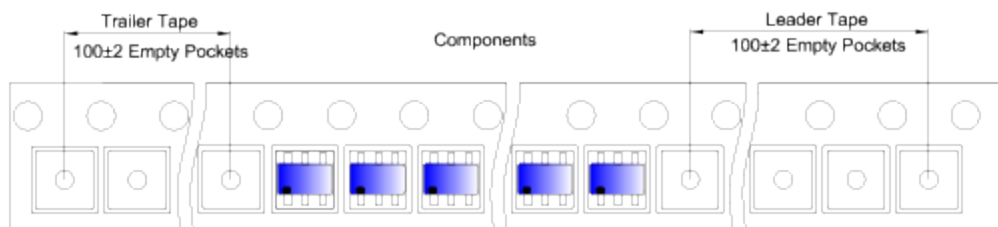


Packaging Description:

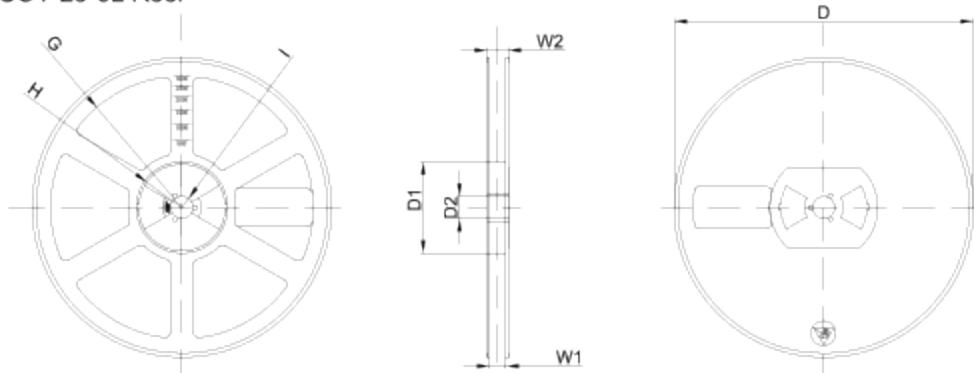
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Dimensions are in millimeter										
Pkg type	a	B	C	d	E	F	P0	P	P1	W
SOT-23-6L	3.17	3.23	1.37	Ø1.55	1.75	3.50	4.00	4.00	2.00	8.00

SOT-23-6L Tape Leader and Trailer



SOT-23-6L Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø180.00	60.00	13.00	R78.00	R25.60	R6.50	9.50	13.10

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	30,000 pcs	203×203×195	120,000 pcs	438×438×220	